



DT1446-04S

Product Summary

| V _{BR (min)} | IPP (max) | C _{T (typ)} |
|-----------------------|-----------|----------------------|
| 6V | 4.7A | 0.55pF |

Description

The DT1446-04S is a high performance device suitable for protecting four high speed I/Os and one V_{CC} . These devices are assembled in SOT363 package. They have high ESD surge capability and low capacitance.

Applications

Typically Used for High Speed Ports such as:

- USB 2.0
- IEEE1394
- HDMI
- Laptop and Personal Computers
- Flat Panel Displays
- Video Graphics Displays
- SIM Ports



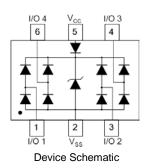
4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

Features

- IEC 61000-4-2 (ESD): Air ±19kV, Contact ±16kV
- Low Channel Input Capacitance of 0.55pF Max
- ESD Protection for four I/Os and one $V_{\mbox{CC}}$
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020 (Lead Free Plating). Solderable per MIL-STD-202, Method 208^(C)
- Weight: 0.006 grams (approximate)



Ordering Information (Note 4)

| Product | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|--------------|------------|---------|--------------------|-----------------|-------------------|
| DT1446-04S-7 | Standard | BE3 | 7 | 8 | 3,000/Tape & Reel |

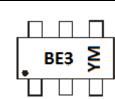
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



3

BE3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: A = 2013) M = Month (ex: 9 = September)

7

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9

Ο

| Dat | te Code Key | | | | | | | | | | | | |
|-----|-------------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| | Year | 20 | 13 | 20 | 14 | 20 | 15 | 20 | 16 | 20 | 17 | 20 | 18 |
| | Code | A | ł | E | 3 | С | | D | | E | | F | |
| | | | | | | | | | | | | | |
| | Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |

6

2

Code

5

D

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol Value | | Unit | Conditions |
|---|-----------------------------------|-----|------|--|
| Peak Pulse Current ,per IEC 61000-4-5 | I _{PP_I/O} | 4.7 | А | I/O to V _{SS} , 8/20µs |
| Operating Voltage (DC) | V _{DC} | 6 | V | V _{CC} to V _{SS} |
| ESD Protection – Contact Discharge | V _{ESD_I/O} | ±16 | kV | I/O to V _{SS} , per IEC 61000-4-2 |
| ESD Frotection – Contact Discharge | $V_{ESD}V_{CC}$ | ±30 | kV | V_{CC} to V_{SS} , per IEC 61000-4-2 |
| ESD Protection – Air Discharge, per IEC 61000-4-2 | V _{ESD_I/O} | ±19 | kV | I/O to V _{SS} , per IEC 61000-4-2 |
| LOD FIDECUDIT - AIL DISCHARGE, PELIEC 01000-4-2 | V _{ESD} _V _{CC} | ±30 | kV | V_{CC} to V_{SS} , per IEC 61000-4-2 |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|------------|------|
| Power Dissipation Typical (Note 5) | PD | 200 | mW |
| Thermal Resistance, Junction to Ambient Typical (Note 5) | R _{0JA} | 625 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to 150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

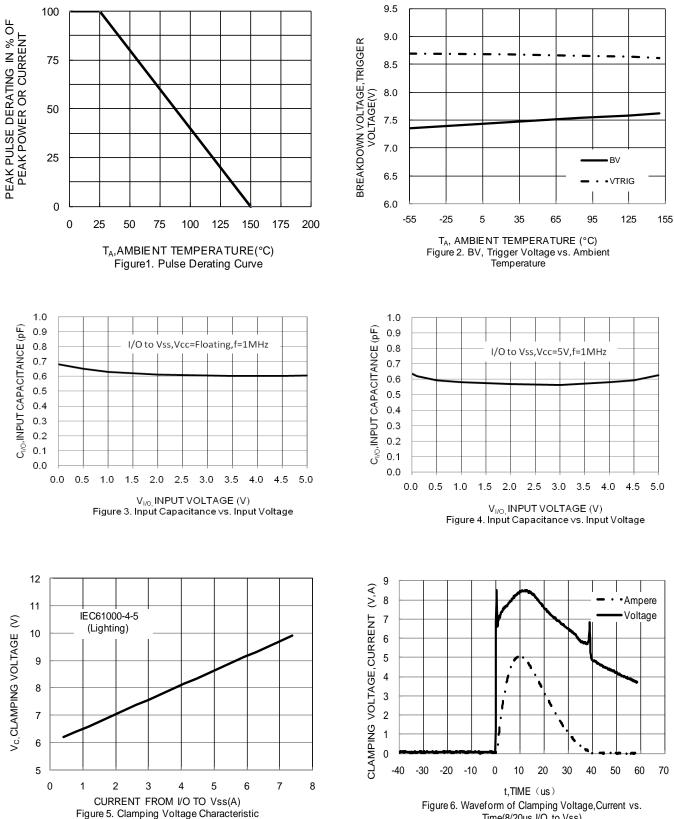
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Conditions |
|---|--|-----|------|------|------|---|
| Reverse Working Voltage | Vrwm | _ | _ | 5.0 | V | V _{CC} to V _{SS} |
| Reverse Current (Note 6) | I _{R(VCC to} V _{SS)} | _ | — | 5.0 | μA | $V_R = V_{RWM} = 5V, V_{CC} \text{ to } V_{SS}$ |
| Reverse Current (Note 6) | I _{R(IO to} V _{SS)} | — | — | 1.0 | μA | $V_R = V_{RWM} = 5V$, any I/O to V_{SS} |
| Reverse Breakdown Voltage | Vbr | 6.0 | — | 9.0 | V | $I_R = 1mA$, V_{CC} to V_{SS} |
| Forward Clamping Voltage | VF | | 0.8 | 1.0 | V | I_F = 15mA, V _{SS} to V _{CC} |
| Reverse Clamping Voltage (Note 7) | V _{C_I/O} | — | 8.5 | — | V | I _{PP} =4.7A, I/O to V _{SS} , 8/20µs |
| ESD Clamping Voltage | Vesd_Vcc | — | 10 | — | V | TLP, 20A, tp = 100ns, V_{CC} to V_{SS} |
| ESD Clamping Voltage | Vesd_i/o | — | 12 | — | V | TLP, 20A, tp = 100ns, I/O to V_{SS} |
| Dynamic Resistance | $R_{DIF}V_{CC}$ | | 0.14 | — | Ω | TLP, 20A, tp = 100ns, V_{CC} to V_{SS} |
| Dynamic Resistance | R _{DIF_I/O} | - | 0.3 | — | Ω | TLP, 20A, tp = 100ns, I/O to V_{SS} |
| Channel Input Capacitance | C _{I/O to} V _{SS} | — | 0.55 | 0.65 | pF | $V_R = 2.5V, V_{CC} = 5V, f = 1MHz$ |
| Channel Input Capacitance | C _{I/O to} V _{SS} | — | 0.65 | — | pF | V_R = 2.5V, V_{CC} = floating, f = 1MHz |
| Variation of Channel Input Capacitance | CI/OMAX-CI/OMIN | _ | 0.03 | _ | pF | $\label{eq:VCC} \begin{split} V_{CC} &= 5V, V_{SS} = 0V, I/O = 2.5V, f = 1MHz, \\ T &= +25^\circ C \ , C_{I/OMAX} - C_{I/OMIN} \end{split}$ |
| Variation of Channel Input Capacitance | C _{I/OMAX} -C _{I/OMIN} | _ | 0.05 | — | pF | $ V_{CC} = floating , V_{SS} = 0V, I/O = 2.5V, $ |

Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com. 6. Short duration pulse test used to minimize self-heating effect.

7. Clamping voltage value is based on an 8x20 $\!\mu s$ peak pulse current (I_{pp}) waveform.



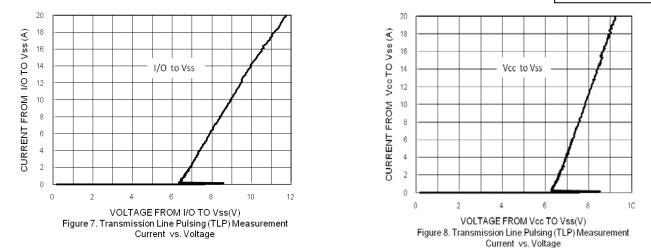
DT1446-04S



Time(8/20us,I/O to Vss)

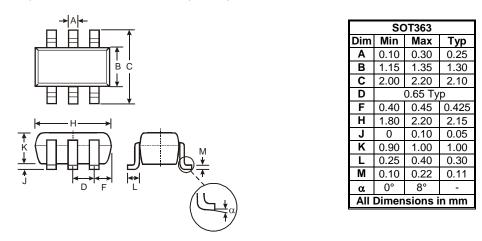


DT1446-04S



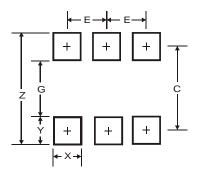
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.5 |
| G | 1.3 |
| Х | 0.42 |
| Y | 0.6 |
| С | 1.9 |
| E | 0.65 |



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